

INFORMATION DISCLOSURE CITATION <small>OCT 22 2003 PTO-1449</small>		CUSTOMER NUMBER 26615	ATTORNEY'S DKT NO. H1178	APPLICATION NO. 10/632,965	
			APPLICANT(S) Haihong WANG et al.	FILING DATE August 4, 2003	GROUP Unassigned 2811
U.S. PATENT DOCUMENTS					
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS
FOREIGN PATENT DOCUMENTS					
EXAMINER'S INITIALS	PATENT NO.	DATE	COUNTRY	CLASS	SUBCLASS
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)					
<u>YU</u>	Copy of co-pending U.S. Patent Application Serial No. 10/653,234, filed September 3, 2003, entitled: "Narrow Body Raised Source/Drain Metal Gate MOSFET," Bin Yu et al.; 27 pages.				
EXAMINER	HUNG YU		DATE CONSIDERED		
			08/23/04		

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